

# MJW0281A (NPN) MJW0302A (PNP)

Preferred Devices

## Complementary NPN-PNP Power Bipolar Transistors

These complementary devices are lower power versions of the popular MJW3281A and MJW1302A audio output transistors. With superior gain linearity and safe operating area performance, these transistors are ideal for high fidelity audio amplifier output stages and other linear applications.

### Features

- Exceptional Safe Operating Area
- NPN/PNP Gain Matching within 10% from 50 mA to 5 A
- Excellent Gain Linearity
- High BVCEO
- High Frequency

### Benefits

- Reliable Performance at Higher Powers
- Symmetrical Characteristics in Complementary Configurations
- Accurate Reproduction of Input Signal
- Greater Dynamic Range
- High Amplifier Bandwidth

### Applications

- High-End Consumer Audio Products
  - ◆Home Amplifiers
  - ◆Home Receivers
- Professional Audio Amplifiers
  - ◆Theater and Stadium Sound Systems
  - ◆Public Address Systems (PAs)

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	260	Vdc
Collector-Base Voltage	$V_{CBO}$	260	Vdc
Emitter-Base Voltage	$V_{EBO}$	5.0	Vdc
Collector-Emitter Voltage – 1.5 V	$V_{CEX}$	260	Vdc
Collector Current – Continuous – Peak (Note 1)	$I_C$	15 30	Adc
Base Current – Continuous	$I_B$	1.5	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$	$P_D$	150	Watts
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	- 65 to +150	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

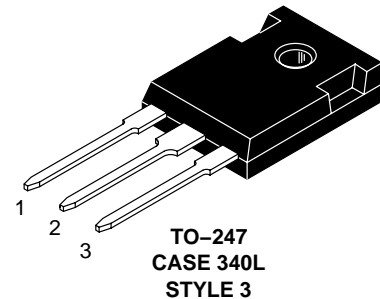
1. Pulse Test: Pulse Width = 5.0 ms, Duty Cycle < 10%.



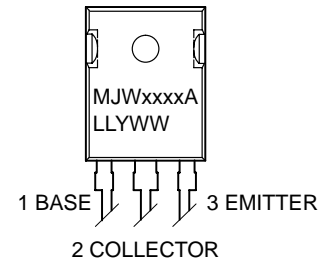
**ON Semiconductor®**

<http://onsemi.com>

**15 AMPERES  
COMPLEMENTARY  
SILICON POWER  
TRANSISTORS  
260 VOLTS  
150 WATTS**



### MARKING DIAGRAM



MJWxxxxA = Device Code  
 xxxx = 0281 OR 0302  
 LL = Location Code  
 Y = Year  
 WW = Work Week

### ORDERING INFORMATION

Device	Package	Shipping
MJW0281A	TO-247	30 Units/Rail
MJW0302A	TO-247	30 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

# MJW0281A (NPN) MJW0302A (PNP)

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.83	$^{\circ}\text{C}/\text{W}$

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^{\circ}\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage ( $I_C = 30\text{ mA}$ , $I_B = 0$ )	$V_{CEO(sus)}$	260	–	V
Collector Cutoff Current ( $V_{CB} = 260\text{ V}$ , $I_E = 0$ )	$I_{CBO}$	–	10	$\mu\text{A}$
Emitter Cutoff Current ( $V_{EB} = 5.0\text{ V}$ , $I_C = 0$ )	$I_{EBO}$	–	5.0	$\mu\text{A}$

### ON CHARACTERISTICS

DC Current Gain ( $I_C = 0.5\text{ A}$ , $V_{CE} = 5.0\text{ V}$ ) ( $I_C = 1.0\text{ A}$ , $V_{CE} = 5.0\text{ V}$ ) ( $I_C = 3.0\text{ A}$ , $V_{CE} = 5.0\text{ V}$ )	$h_{FE}$	75 75 75	150 150 150	–
Collector-Emitter Saturation Voltage ( $I_C = 5.0\text{ A}$ , $I_B = 0.5\text{ A}$ )	$V_{CE(sat)}$	–	1.0	V
Base-Emitter On Voltage ( $I_C = 5.0\text{ A}$ , $V_{CE} = 5.0\text{ V}$ )	$V_{BE(on)}$	–	1.2	V

### DYNAMIC CHARACTERISTICS

Current-Gain – Bandwidth Product ( $I_C = 1.0\text{ A}$ , $V_{CE} = 5.0\text{ V}$ , $f_{test} = 1.0\text{ MHz}$ )	$f_T$	30	–	MHz
Output Capacitance ( $V_{CB} = 10\text{ V}$ , $I_E = 0$ , $f_{test} = 1.0\text{ MHz}$ )	$C_{ob}$	–	400	pF

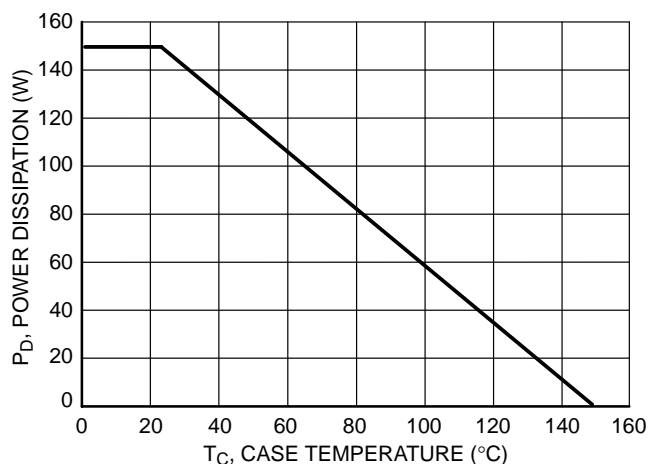


Figure 1. Power Derating

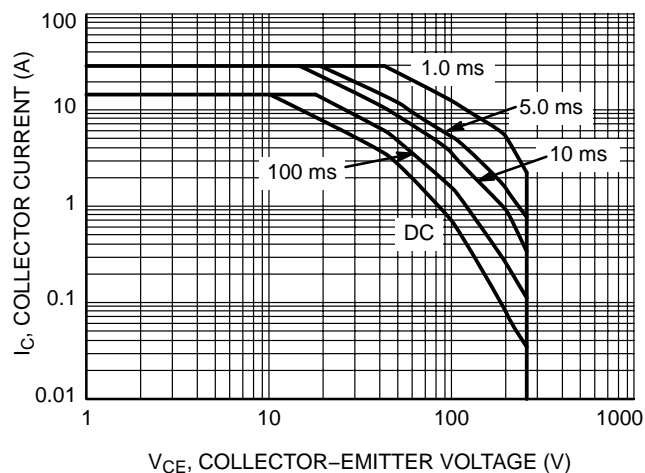


Figure 2. Safe Operating Area

# MJW0281A (NPN) MJW0302A (PNP)

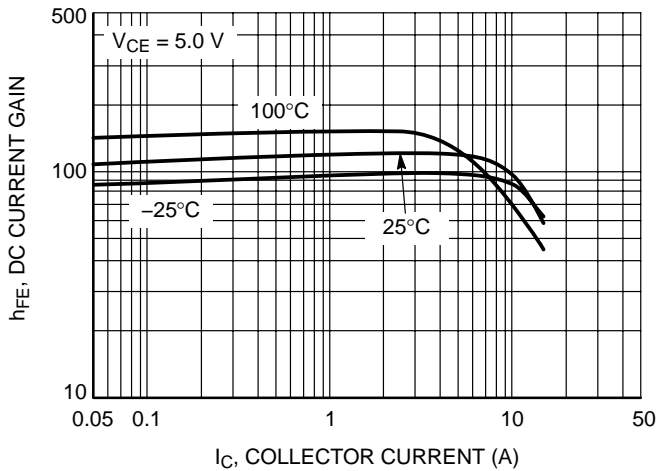


Figure 3. MJW0281A DC Current Gain

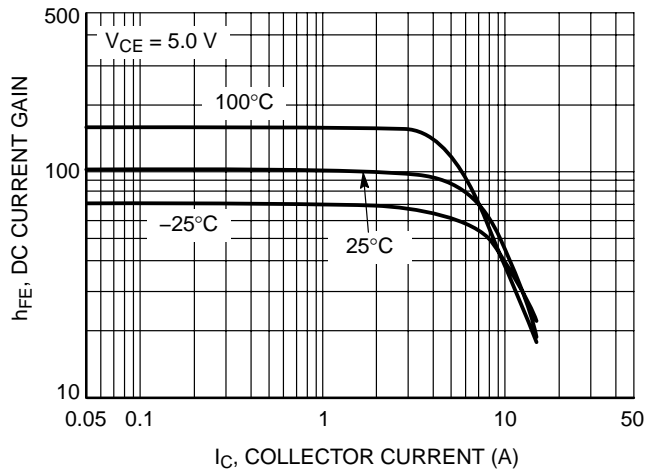


Figure 4. MJW0302A DC Current Gain

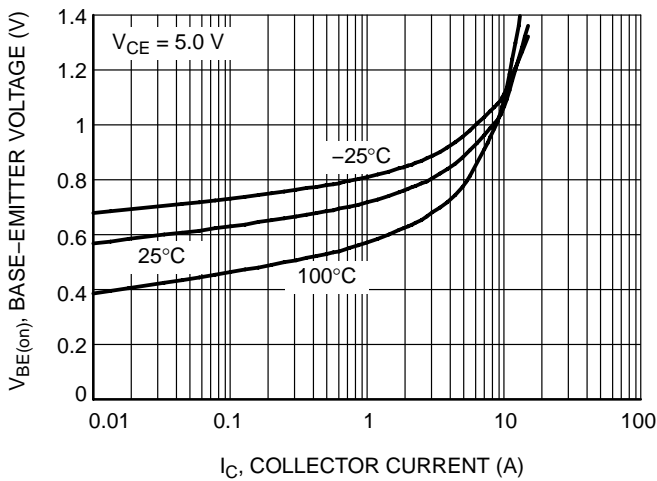


Figure 5. MJW0281A Base-Emitter Voltage

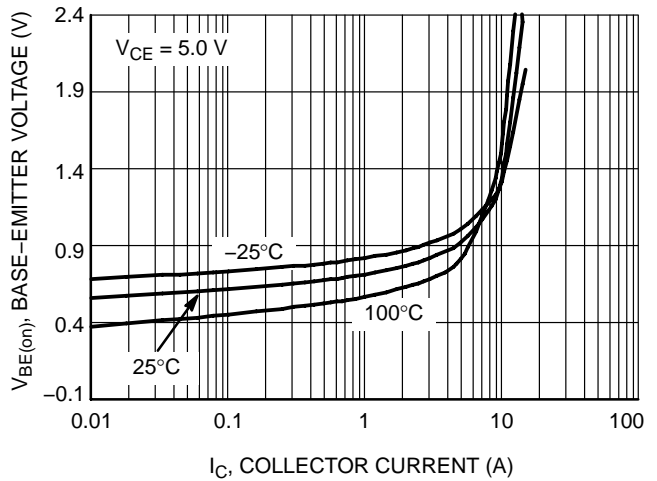


Figure 6. MJW0302A Base-Emitter Voltage

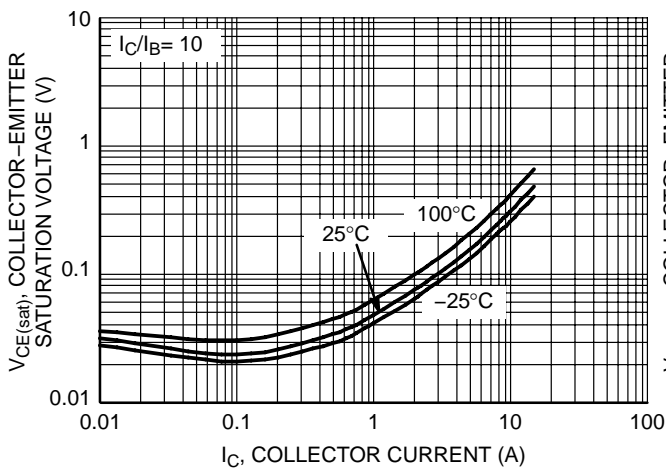


Figure 7. MJW0281A Saturation Voltage

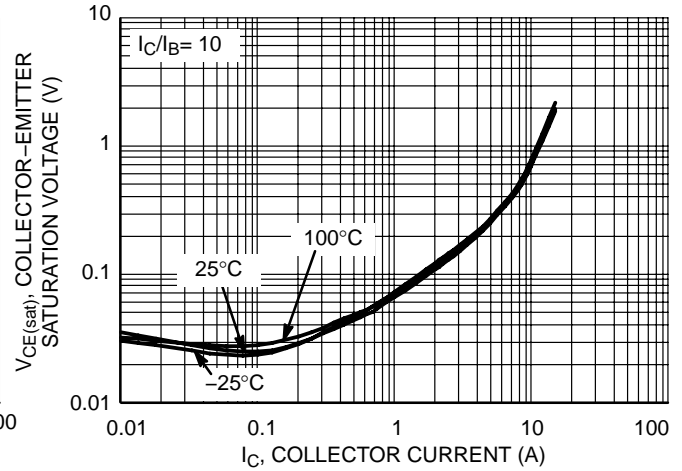


Figure 8. MJW0302A Saturation Voltage

## MJW0281A (NPN) MJW0302A (PNP)

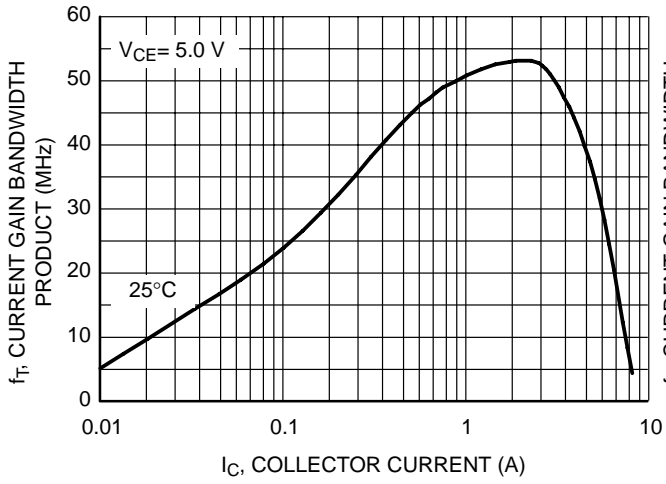


Figure 9. MJW0281A Current Gain Bandwidth Product

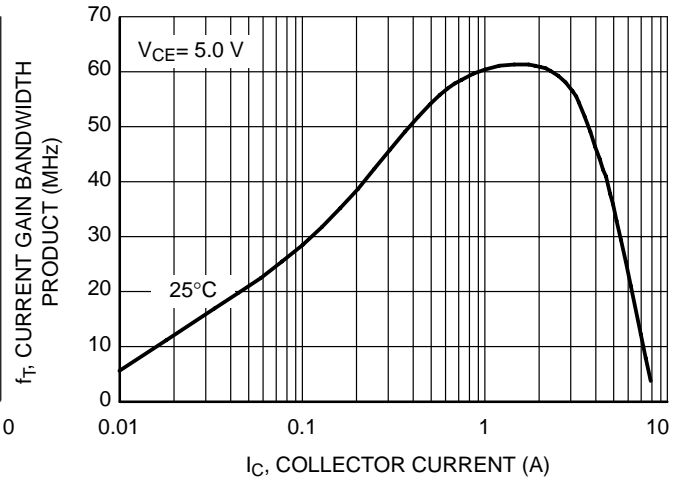
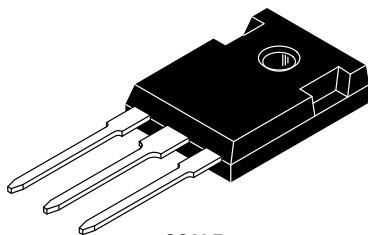


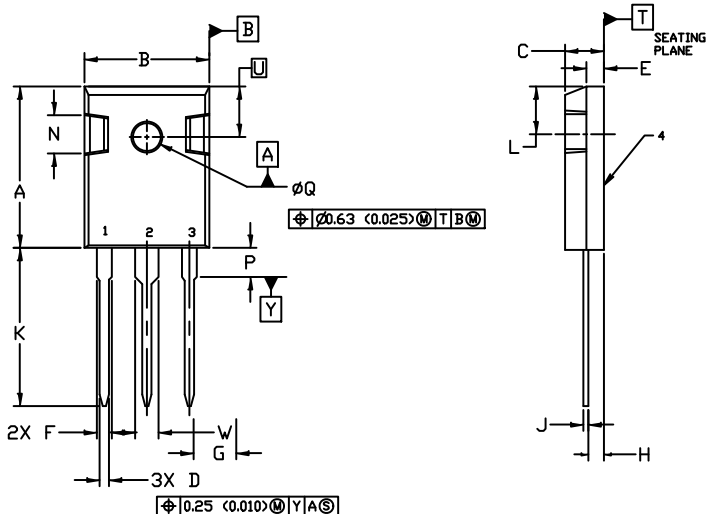
Figure 10. MJW0302A Current Gain Bandwidth Product



TO-247  
CASE 340L  
ISSUE G

DATE 06 OCT 2021

SCALE 1:1

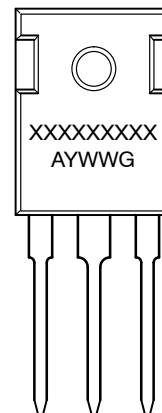


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER

DIM	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	20.32	21.08	0.800	0.830
B	15.75	16.26	0.620	0.640
C	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
E	1.90	2.60	0.075	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
H	1.50	2.49	0.059	0.098
J	0.40	0.80	0.016	0.031
K	19.81	20.83	0.780	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
P	----	4.50	----	0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242 BSC	
W	2.87	3.12	0.113	0.123

GENERIC  
MARKING DIAGRAM\*



- |  |  |  |  |
|--|--|--|--|
| <p>STYLE 1:<br/>PIN 1. GATE<br/>2. DRAIN<br/>3. SOURCE<br/>4. DRAIN</p>  | <p>STYLE 2:<br/>PIN 1. ANODE<br/>2. CATHODE (S)<br/>3. ANODE 2<br/>4. CATHODES (S)</p>               | <p>STYLE 3:<br/>PIN 1. BASE<br/>2. COLLECTOR<br/>3. EMITTER<br/>4. COLLECTOR</p> | <p>STYLE 4:<br/>PIN 1. GATE<br/>2. COLLECTOR<br/>3. EMITTER<br/>4. COLLECTOR</p> |
| <p>STYLE 5:<br/>PIN 1. CATHODE<br/>2. ANODE<br/>3. GATE<br/>4. ANODE</p> | <p>STYLE 6:<br/>PIN 1. MAIN TERMINAL 1<br/>2. MAIN TERMINAL 2<br/>3. GATE<br/>4. MAIN TERMINAL 2</p> |  |  |

- XXXXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	TO-247	PAGE 1 OF 1

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